## NSN 5962-01-432-8568

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| Maximum Power Dissipation Rating:  |
|--|
| 1.0 watts  |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| Storage Tempurature Range:   |
| -65.0/+150.0 degrees celsius   |
| End Application:   |
| C10661b/aas38 e/i fscm 09205   |
| Features Provided:   |
| Programmed and electrostatic sensitive and burn in   |
| Inclosure Material:  |
| Ceramic  |
| Inclosure Configuration:   |
| Leadless flat pack   |
| Voltage Rating And Type Per Characteristic:  |
| -0.3 volts input and 6.25 volts input  |
| Time Rating Per Chacteristic:  |
| 120.00 nanoseconds af output megawatts   |
| Memory Device Type:  |
| Eeprom   |
| Special Features:  |
| Made from smd 5962-8863402ya   |
| Test Data Document:  |
| $96906 \hbox{-mil-std-883 standard (includes industry or association standards, \ individual manufactureer standards, \ etc.)}.$ |
| Terminal Type And Quantity:  |
| 32 leadless  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| Yes - demil/mli  |
| Fiig:  |
| A458a0   |
|  |
|  |